

We are so pleased to announce the recipients of AM-FPD '21 Award.

They will be presented the award in the Opening Session of AM-FPD '22 on July 5, 2022.

AM-FPD '21 Best Paper Award

2_3 Peeling Technique by Two-Dimensional MoSe₂ Atomic Layer for Bifacial-Flexible Cu (In,Ga) Se₂ Solar Cells

T. Nishimura^{1,*}, A. Mavlonov¹, J. Chantana¹, Y. Kawano¹ and T. Minemoto¹
¹ *Ritsumeikan Univ., JAPAN*

AM-FPD '21 Poster Paper Award

P_02 Characteristics of Argon-Ion-Implanted Amorphous-InGaZnO

K. Yasuta^{1,*}, T. Ui¹, T. Ikeda², D. Matsuo², T. Sakai², S. Dohi¹,
Y. Setoguchi², E. Takahashi², Y. Andoh² and J. Tatemichi¹
¹ *NISSIN ION EQUIPMENT CO., LTD., JAPAN*, ² *NISSIN ELECTRIC CO., LTD., JAPAN*

AM-FPD '21 Student Award

Htet Su Wai, *Kochi Univ. of Technol., Japan*

4_3 Oxygen Ratio Effect on Zinc Oxide Films Fabricated by Radio Frequency Magnetron Sputtering for Photoluminescence Type Gas Sensor Application

AMFPD '21-ECS Japan Section Young Researcher Award

Juan Paolo Bermundo, *Nara Inst. of Sci. and Technol.(NAIST), Japan,*

5_2 High-k Solution Processed Hybrid Gate Insulators for Amorphous Oxide Thin-Film Transistors and its Temperature and Thickness Dependence